In the early 1950s, Bohm and Pines (BP) developed the random-phase approximation (RPA) theory and revealed the plasmon as an emergent collective mode in metals. In this paper, for the first time ever since the original BP theory, a novel collective mode is predicted to emerge in the dilute electron liquid. The electronic compressibility of this mode is negative and thus dielectric catastrophe appears, predicted by a theory that goes far beyond RPA and fully satisfies various sum rules, constraints, and asymptotic behavior. While the plasmon occurs by the coherent excitations of mutually uncorrelated electrons and holes, the new mode is associated with the excitations of a large collection of excitons (or tightly bound electron-hole pairs). Mathematically, this excitonic collective mode is intimately connected with a newly discovered singularity in the dielectric function in the electron liquid. This collective mode should add a new dimension to plasmonics in nanotechnology in the future.

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Emergence of an excitonic collective mode in the dilute electron gas

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By comparing two expressions for the polarization function $\Pi(q, i\omega)$ given in terms of two different local-field factors, $G_i(q, i\omega)$ and $G_s(q, i\omega)$, we have derived the kinetic-energy-fluctuation (or sixth-power) sum rule for the momentum distribution function $n(p)$ in the three-dimensional electron gas. With use of this sum rule, together with the total-number (or second-power) and the kinetic-energy (or fourth-power) sum rules, we have obtained $n(p)$ in the low-density electron gas at negative compressibility (namely, $r_s > 5.25$ with $r_s$ being the conventional density parameter) up to $r_s \approx 22$ by improving on the interpolation scheme due to Gori-Georgi and Ziesche proposed in 2002. The obtained results for $n(p)$ combined with the improved form for $G_i(q, i\omega + i0^+)$ are employed to calculate the dynamical structure factor $S(q, \omega)$ to reveal that a giant peak, even bigger than the plasmon peak, originating from an excitonic collective mode made of electron-hole pair excitations, emerges in the low-$\omega$ region at $|q| \approx 2p_F$ (from $p_F$: the Fermi wave number). Connected with this mode, we have discovered a singular point in the retarded dielectric function at $\omega = 0$ and $|q| \approx 2p_F$.

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I. INTRODUCTION

The electron gas, an assembly of $N$ electrons embedded in a uniform positive rigid background, has been investigated for a very long time, not only because it is relevant in understanding the exchange-correlation effects in simple metals and semiconductors, but also because it provides indispensable information for the actual implementation of the density functional theory (DFT), especially in its local density approximation (LDA) [1].

From a physical point of view, we may claim that this system is even more important in the low-density regime (namely, $p_Fa_0 \ll 1$ with $p_F$ the Fermi wave number and $a_0$ the lattice constant), because in this regime the first-principles Hamiltonian to describe conduction electrons in a metal is universally reduced to the one for the electron gas, leading us to recognize that understanding the physical properties of the dilute electron gas is nothing but revealing the universal electron-correlation behavior of actual dilute metals.

The dilute electron gas, however, is not well understood; the thermodynamic quantities, such as the correlation energy $\varepsilon_c$ and the compressibility $\kappa$, are accurately obtained as a function of the density parameter $r_s$ by the Green’s function Monte Carlo (GFMC) method [2] and the interpolation formulas to reproduce the GFMC data [3,4], where $r_s$ is defined by $r_s = (4\pi n/3)^{-1/3}/a_B = (\alpha p_F a_B)^{-1}$ with $n = N/\Omega$, the electron density, $\Omega$, the total volume of the system, $\alpha = (4/\sqrt{\pi})^{1/3} \approx 0.5211$, and $a_B$ the Bohr radius. The diffusion Monte Carlo (DMC) calculations are done to analyze the ground-state phases, including spin polarization, in the wide range of $r_s$ [5] and recently for $0.5 \leq r_s \leq 20$ in more detail [6], but we do not know the precise behavior of other physical quantities, such as the momentum distribution function $n(p)$ for $r_s > 5$.

It is true that some quantum Monte Carlo calculations are done to obtain $n(p)$ for $r_s \leq 10$ [7,8], but the results are not very accurate due probably to large size effects and improper starting trial functions, judging from the assessment of their accuracy by the sum rules for $n(p)$ [9,10]. As for the dynamical structure factor $S(q, \omega)$, no reliable data are available in the dilute metallic regime.

One of the characteristic features of the dilute electron gas is the appearance of “dielectric catastrophe” associated with the divergence of $\kappa$ at $r_s = r_s^c = 5.25$ followed by negative $\kappa$ for $r_s > r_s^c$ [11,12], implying that the static polarization function $\Pi(q, 0)$ in the long-wavelength limit is also negative (and thus dielectrically anomalous) owing to the compressibility sum rule, $\lim_{q \to 0} \Pi(q, 0) = n^2\kappa \Omega_1$. [13] This anomaly for $r_s > r_s^c$ brings about the curious behavior of the ion-ion pair correlation function in expanded liquid alkali metals [14–16], but it does not induce any instabilities in the electron gas itself, as long as $1/\kappa$ changes continuously from positive to negative through the point of $1/\kappa = 0$ [17], because the electron-electron effective interaction is not determined only by the dielectric function $\varepsilon(q, i\omega + i0^+) = 1 + V(q, \omega)\Pi(q, i\omega)$ with $V(q) = 4\pi e^2/(\Omega q^2)$ the bare Coulomb interaction [18], excluding the occurrence of CDW-type instabilities at $r_s = r_s^c$ [19].

By analyzing $\varepsilon^{\alpha}(q, \omega)$, we identify the physical origin of this divergence of $\kappa$ as the “enhanced excitonic effect” or the effect of strong electron-hole attraction in an electron-hole single-pair excitation [20]. For $r_s > r_s^c$, by considering causality, Takayanagi and Lipparini [21] have concluded that $\Pi(q, i\omega)$ contains an anomalous part $\Pi_\alpha(q, i\omega)$ made of a single pair of poles at $i\omega = \pm i\tilde{\omega}_\alpha(q)$ in the form of

$$\Pi_\alpha(q, i\omega) = \frac{1}{V(q)} \frac{ne^2}{m} \frac{f_{\alpha\alpha}(q)}{\omega^2 - \tilde{\omega}_\alpha(q)^2},$$

with $m$ the mass of a free electron. These poles at which $\Pi(q, i\omega)$ diverges, however, do not give any prominent structures in the observable physical quantity $S(q, \omega)$, which can be estimated by $S(q, \omega) = -\text{Im}Q^R(q, \omega)/\pi$ for $\omega > 0$ at zero temperature ($T = 0$) with the retarded charge response function $Q^R(q, \omega)$, given by

$$Q^R(q, \omega) = \frac{\Pi(q, \omega + i0^+)}{1 + V(q)\Pi(q, \omega + i0^+)}.$$

Then a couple of questions arise: what is the physical role of these poles and how the strong excitonic effect manifests...
itself in $S(q,\omega)$ for $r_s > r_s^c$? We shall address these questions by accurately determining $\omega_{ex}(q)$, “the oscillator strength” of the pole $f_{ex}(q)$, and $S(q,\omega)$ for $r_s$ from $r_s^c$ up to about 20 in which the ground state has already been confirmed to be a paramagnetic metal [6].

A straightforward way of obtaining accurate results for $S(q,\omega)$ is to perform the highly self-consistent calculation in the GW’ scheme [22] which includes the vertex function $\Gamma$ satisfying the Ward identity (WI) [23,24], just as done for $S(q,\omega)$ for $r_s \leq 5$ [25], but it turns out that this GW’ does not work well in the dielectric-catastrophe regime. Thus it is revised into the GW’$_W$ scheme [10,26] to obtain the self-consistent results for $S(q,\omega)$ as well as $n(p)$ up to $r_s = 10$, but there still remains the problem of reaching a fully self-consistent solution for $r_s > 10$. Confronted with this difficulty, we will take the following strategy: First, we reconsider the parametrization scheme for determining $n(p)$ due to Gori-Giorgi and Ziesche (GZ) [27], who interpolate the accurate data for $n(p)$ in the effective potential expansion (EPX) method [9] for $1 \leq r_s \leq 5$ with that in the Wigner-crystal limit ($r_s \gg 10$), together with the two sum rules, one for the total number and the other for the total kinetic energy [9], expressed as

$$\sum_{p\sigma} n(p) = N, \quad (3)$$

$$\sum_{p\sigma} \epsilon_p n(p) = N \langle \epsilon_p \rangle = N \left( \frac{3}{5} E_F - \epsilon_c - \frac{\partial \epsilon_c}{\partial r_s} \right), \quad (4)$$

with $\sigma$ the spin variable, $\epsilon_p = p^2/(2m)$, and $E_F = p_F^2/(2m)$ the Fermi energy. This GZ scheme can give rather accurate $n(p)$ for $r_s \lesssim 12$. Here we shall improve on it by increasing the number of input data for $n(p)$ that we obtain up to $r_s = 10$ in GW’$_W$. We also use, in addition to the above two, the third sum rule for the total kinetic-energy fluctuation, written as

$$\sum_{p\sigma} \epsilon_p^2 n(p) = N \left( \langle \epsilon_p^2 \rangle - \langle \epsilon_p \rangle^2 \right). \quad (5)$$

We shall derive this sum rule in Sec. II with giving a concrete value for the right-hand side of Eq. (5).

Second, once $n(p)$ is known, we can calculate $\Pi(q,i\omega)$ by the formula given in GW’$_W$ as

$$\Pi(q,i\omega) = \frac{\Pi_{W}(q,i\omega)}{1 - V(q) G_{+}(q,i\omega) \Pi_{W}(q,i\omega)}, \quad (6)$$

where $\Pi_{W}(q,i\omega)$ is defined as

$$\Pi_{W}(q,i\omega) = \sum_{p\sigma} \frac{n(p + q) - n(p)}{i\omega - \epsilon_{p+q} + \epsilon_p}, \quad (7)$$

with $G_{+}(q,i\omega)$ the local-field factor as introduced by Richardson and Ashcroft [28]. This factor is different from the conventional local-field factor $G_{+}(q,i\omega)$ [18], with which $\Pi(q,i\omega)$ is expressed in another way as

$$\Pi(q,i\omega) = \frac{\Pi_{0}(q,i\omega)}{1 - V(q) G_{+}(q,i\omega) \Pi_{0}(q,i\omega)}, \quad (8)$$

with $\Pi_{0}(q,i\omega)$ the Lindhard function, given by

$$\Pi_{0}(q,i\omega) = \sum_{p\sigma} \frac{n_0(p + q) - n_0(p)}{i\omega - \epsilon_{p+q} + \epsilon_p}, \quad (9)$$

with $n_0(p) = \theta(p_F - |p|)$ the step function. The obtained $\Pi(q,i\omega)$ can be used to determine both $\omega_{ex}(q)$ and $f_{ex}(q)$ by the analysis of its divergent property.

Finally, we need to make an analytic continuation of $\Pi(q,i\omega)$ into $\Pi(q,\omega + i0^+)$ to calculate $S(q,\omega)$. There are two ingredients, $\Pi_{W}(q,\omega + i0^+)$ and $G_{+}(q,\omega + i0^+)$, in this analytic continuation. The former can be obtained by the direct calculation through Eq. (7) with $\omega + i0^+$ in place of $i\omega$. As for the latter, we find it better to slightly modify $G_{+}(q,i\omega)$ from the original formula [29], so that we can not only obtain much more accurate $\epsilon_c$ in a wide range of $r_s$ by the adiabatic connection formula [29] but also eliminate unphysical divergences from $G_{+}(q,\omega + i0^+)$. In accordance with the above strategy, we have successfully performed the calculation and obtained the results of both $n(p)$ and $S(q,\omega)$ for $r_s$ up to over 20 to reveal that a giant peak other than the conventional plasmon one emerges in $S(q,\omega)$ for $r_s \gtrsim 10$, evolving into a predominant peak for $r_s > 10$, as shown in Fig. 1. Concomitantly a singular behavior is found in $S(q,\omega)$ at zero temperature at (a) a usual metallic density $r_s = 4$, in which the plasmon peak dominates, and (b) a very dilute density $r_s = 22$, in which an excitonic collective peak, much bigger than the plasmon peak, emerges.
II. MOMENTUM DISTRIBUTION FUNCTION

A. Hamiltonian

Apart from a constant term, the first-principles Hamiltonian $H$ for a system of $N$ electrons interacting with each other through the Coulomb interaction in a periodic one-body potential is written in the plane-wave basis as [30]

$$H = H_0 + V + U,$$  \hspace{1cm} (10)

with

$$H_0 = \sum_{p\sigma} E_p c_{p\sigma}^+ c_{p\sigma},$$  \hspace{1cm} (11)

$$V = \frac{1}{2} \sum_{q \neq 0} \sum_{p \sigma} \sum_{p' \sigma'} V(q) c_{p+q\sigma}^+ c_{p'q\sigma'}^+ c_{p\sigma} c_{p'\sigma'},$$  \hspace{1cm} (12)

$$U = \sum_{p \sigma} U_{p,p+G} c_{p\sigma}^+ c_{p+G\sigma},$$  \hspace{1cm} (13)

where $c_{p\sigma}$ is the annihilation operator of an electron with momentum $p$ and spin $\sigma$ and $G$ is a reciprocal-lattice vector. If the electron density $n (= N/\Omega_0)$ is so low as to satisfy the condition of $p v_{\text{dlo}} \ll 1$, we may virtually regard $|G|$, which is $2\pi/\Omega_0$ or larger, as an infinite number, allowing us to neglect all terms in $U$. Then the system can be described by the Hamiltonian reduced in the form of $H = H_0 + V$, which is nothing but the electron gas and with which we shall be concerned in this paper.

B. Momentum distribution function

At zero temperature ($T = 0$), the momentum distribution function $n(p)$ is defined as an expectation value

$$n(p) = \langle c_{p\sigma}^+ c_{p\sigma} \rangle,$$  \hspace{1cm} (14)

evaluated with respect to the ground state $\Psi_0$. This quantity is independent of spin for a paramagnetic $\Psi_0$.

The short-range electron correlation determines the asymptotic behavior of $n(p)$ as well as the structure factor $S(q)$ and their exact forms are given as [31]

$$\Omega \left( \frac{ab}{4\pi} \right)^2 \lim_{|p| \to \infty} \left| |p|^8 n(p) \right| = \left( \frac{ab}{8\pi} \right) \lim_{|q| \to \infty} \left| q|^4 S(q) \right| = g(0),$$  \hspace{1cm} (15)

where $g(0)$ is the on-top value of the pair distribution function. We can rewrite Eq. (15) as

$$\lim_{|p| \to \infty} n(p) = \frac{8}{9} \left( \frac{ar_s}{\pi} \right)^2 \frac{p^8}{|p|^8} g(0),$$  \hspace{1cm} (16)

dictating the asymptotic behavior of $n(p)$. By using $V(q)$ in the electron-electron ladder approximation, Yasuhara derived a formula for $g(0)$ as [32,33]

$$g(0) = g_Y(0) \equiv \frac{1}{2} \left( \frac{\sqrt{4ar_s/\pi}}{I_1(2\sqrt{4ar_s/\pi})} \right)^2,$$  \hspace{1cm} (17)

where $I_1(x)$ is the modified Bessel function of the first kind. There are three other parameterization formulas for $g(0)$; by the phase-shift analysis of the two-electron problem, Overhauser [34] derived one formula $g_{O}(0)$ and Gori-Giorgi and Perdew [35] improved on it to give another one $g_{GP}(0)$, both of which are intended to provide accurate results of $g(0)$ for $r_s \leq 10$. More recently, Spink, Needs, and Drummond (SND) [36] provided yet another formula $g_{SND}(0)$, which reproduces their DMC data for $r_s \leq 20$. The results of these formulas are given as a function of $r_s$ in Fig. 2. We see immediately that they are essentially the same for $r_s \leq 10$. For $r_s \leq 20$, Yasuhara’s and SND’s give about the same results, but the latter deteriorates very much soon after $r_s$ goes beyond 20. [Actually, SND gives unphysical negative $g(0)$ for $r_s > 24.26$.] Thus, apparently, the best choice for $g(0)$ is Yasuhara’s formula $g_Y(0)$ in Eq. (17) which will be mainly employed over a wide range of $r_s$ hereafter.

C. Sum rules

Let us derive the three sum rules, Eqs. (3)–(5), for $n(p)$. The static charge response function $Q_e(q,0)$ in the electron gas is calculated by Moroni, Ceperley, and Senatore (MCS) [36] in DMC for $r_s < 10$, giving the numerical data for $\Pi(q,0)$. With use of Eq. (8), we obtain

$$1 \frac{1}{\Pi(q,0)} = 1 \frac{1}{\Pi_0(q,0)} - V(q) G_e(q,0).$$  \hspace{1cm} (18)

This may be regarded as the definition of the static local-field factor $G_e(q,0)$. The DMC data of $\Pi(q,0)$, together with the

Fig. 2. Comparison of various formulas for the on-top pair distribution function $g(0)$ plotted as a function of $r_s$ over a very wide range.

FIG. 2. Comparison of various formulas for the on-top pair distribution function $g(0)$ plotted as a function of $r_s$ over a very wide range.
well-known analytical result of $\Pi_0(q,0)$, determine $G_+(q,0)$, which is parametrized as a function of $r_s$ and $q (= |q|)$ [36]. In particular, in the limit of $q \to \infty$, $G_+(q,0)$ is known as
\begin{equation}
G_+(q,0) \longrightarrow C(r_s) \left( \frac{q}{p_F} \right)^2 + B(r_s),
\end{equation}
where the constants $B(r_s)$ and $C(r_s)$ are given by
\begin{equation}
B(r_s) = B_{MCS}(r_s) \equiv 1 + (a_1 + a_2 r_s) \sqrt{r_s} \frac{1}{3 + (b_1 + b_2 r_s) \sqrt{r_s}},
\end{equation}
\begin{equation}
C(r_s) = \frac{\pi}{4} a_{rs} \left( -\frac{\partial e_c(r_s)}{\partial r_s} - r_s \frac{\partial e_c(r_s)}{\partial r_s} \right),
\end{equation}
with $a_1 = 2.15, a_2 = 0.435, b_1 = 1.57, b_2 = 0.409$, and $e_c(r_s)$ (in Ry) in the parametrization scheme due to Perdew and Wang [4].

On the other hand, we obtain another expression for $\Pi(q,0)^{-1}$ with the use of Eq. (6) as
\begin{equation}
\frac{1}{\Pi(q,0)} = \frac{1}{\Pi_0(q,0)} + (G_+(q,0) - G_+(q,0)|V(q).
\end{equation}
Now $\Pi_0(q,0)$ in Eq. (7) is reduced to
\begin{equation}
\Pi_0(q,0) = \frac{\Omega_m}{\Omega} \frac{m_{pe}}{\pi^2} \int_0^{\infty} dx n(x) x \ln \left( \frac{x + z}{x - z} \right),
\end{equation}
with $x = |p|/p_F, z = |q|/2p_F$, and $n(x) = n(p)$. This equation can be asymptotically expanded as
\begin{equation}
\Pi_0(q,0) = \frac{\Omega_m}{\Omega} \frac{m_{pe}}{\pi^2} \left( \frac{I_2}{z^2} + \frac{1}{3} \frac{I_4}{z^4} + \frac{1}{5} \frac{I_6}{z^6} + \cdots \right),
\end{equation}
where the $n$th-power integral $I_n$ is defined as
\begin{equation}
I_n = \int_0^\infty dx n(x) x^n.
\end{equation}
A similar asymptotic expansion can be made for $\Pi_0(q,0)$ with $I_n$ replaced by $I_n^{(0)} = 1/(n + 1)$. Then, by comparing both sides of Eq. (24) order by order and taking the large-$q$ limit, we obtain the following set of equations:
\begin{equation}
I_2 = \frac{1}{3},
\end{equation}
\begin{equation}
I_4 = \frac{2}{5} + \frac{\alpha_r}{3} \left[ -\frac{\partial e_c(r_s)}{\partial r_s} - r_s \frac{\partial e_c(r_s)}{\partial r_s} \right],
\end{equation}
\begin{equation}
I_6 = \frac{2}{15} + \frac{\alpha_r}{9\pi} \left[ B(r_s) - \frac{2}{5} - \frac{2}{3} r_s \right] g(0).
\end{equation}
These equations correspond to Eqs. (3)-(5), respectively, and thus the sum rules are now proved. Note that with use of $I_n$ and $E_F = 1/(\alpha_r^2 r_s^3)$ (in Ry), we can write the average kinetic energy
\begin{equation}
\langle KE \rangle, the fluctuation of kinetic energy $\Delta KE$, and $\Pi_{W}(0,0)$ as
\begin{equation}
\langle KE \rangle = \langle e_p \rangle = 3 I_4 E_F,
\end{equation}
\begin{equation}
\Delta KE = \sqrt{\langle (e_p - \langle e_p \rangle)^2 \rangle} = \sqrt{3 I_6 - 9 I_4^2} E_F,
\end{equation}
\begin{equation}
\Pi_{W}(0,0) \longrightarrow \Pi_{W}(0,0) = \frac{\alpha_r}{\pi r_s} I_0.
\end{equation}

**D. Parametrization form of $n(p)$**

Following Gori-Giorgi and Ziesche (GZ) [27], we consider $n(x)$ in the parametrization form of
\begin{equation}
n(x) = \begin{cases}
      n_0 - \frac{n_0 - n_0}{G(0)} G(x_-) & \text{for } x < 1, \\
      n_+ - \frac{n_+}{G(0)} G(x_+) & \text{for } x > 1,
\end{cases}
\end{equation}
where $x_-$ and $x_+$ are, respectively, introduced as
\begin{equation}
x_- = a_- r_s \frac{\alpha_r}{2\pi^2} \frac{G(0)}{n_0} \frac{1}{1-x} + b(r_s) \frac{\pi}{r_s} \frac{\sqrt{3} \ln 2}{4} \frac{\pi}{G(0)} 4 \frac{1}{4} \frac{n_+}{G(0)} (x - 1)^2 F_{\infty}(x).
\end{equation}
Here $G(x)$ is the Kulik function [38], defined as
\begin{equation}
G(x) = \frac{\int_0^\infty \frac{du}{R(u)} u R(u) - R(y)}{R(u) u + y - u - y} \left| \frac{\pi}{4} x \right| \ln x + \cdots,
\end{equation}
with $R(u) = 1 - u \arctan(1/u)$. This function appears in the calculation of $n(x)$ in the random-phase approximation (RPA) and its asymptotic behavior may be summarized as follows; in the small-$x$ limit,
\begin{equation}
G(x \ll 1) = G(0) + \frac{\pi}{4} \sqrt{3} x \ln x + \cdots,
\end{equation}
with
\begin{equation}
G(0) = \frac{\int_0^\infty \frac{du}{R(u)} \arctan \frac{1}{u}}{\int_0^\infty \frac{du}{R(u)}} = 3.35333 \cdots.
\end{equation}
while in the large-$x$ limit, we obtain
\begin{equation}
G(x \gg 1) = \frac{\pi}{6} (1 - \ln 2) \frac{1}{x^2} + \cdots.
\end{equation}
In accordance with this asymptotic behavior of $G(x), n(x)$ in Eq. (34) behaves in the following way at various limits: In the limit of $x \to 0$,
\begin{equation}
n(x) \longrightarrow n_0 - \frac{F''(0)}{2} x^2 \left( \frac{\pi}{4} \frac{\alpha_r}{b(r_s)} \right)^2 x^2.
\end{equation}
By a simple interpolation between high- and low-density limits of the coefficient of the $x^2$ term in Eq. (41), GZ deduced $b(r_s)$
to be the form of
\[
 b(r_s) = \left(1 + 0.0009376925 r_s^{13/4}\right)^{1/2}. \tag{42}
\]
We adopt this form for \(b(r_s)\). In the limit of \(x \to 1\), 
\[
n(x) \xrightarrow{x \to 1} n_\pm \pm A_\pm(r_s)[1 - |x| \ln |1 - x|], \tag{43}
\]
with \(A_\pm(r_s)\) “the Fermi-edge coefficient” or the coefficient of the logarithmic singularity of the derivative of \(n(x)\) at \(x = 1 \pm 0^\circ\), given by
\[
 A_\pm(r_s) = \frac{1}{4} \left(\frac{\pi}{4} + \sqrt{3}\right) \left(\frac{a(r_s)}{\pi}\right)^{1/2} \approx 0.256 \sqrt{r_s} a_\pm(r_s). \tag{44}
\]
If the electron-hole symmetry strictly holds in the electronic excitations, we obtain \(A_-(r_s) = A_+(r_s)\), as was assumed by GZ, but at low densities in which electron-hole excitations are not restricted only near the Fermi surface and/or the dispersion of a quasielectron is different from that of a quasihole, the symmetry will be broken in general, requiring us to determine \(A_-(r_s)\) and \(A_+(r_s)\) separately. Finally in the limit of \(x \gg 1\),
\[
n(x) \xrightarrow{x \to \infty} \frac{8}{9} \frac{a(r_s)}{x^2} g(0). \tag{45}
\]
If \(F_\infty(x)\) approaches unity at \(x \to \infty\), Eq. (45) is reduced to Eq. (16), as it should be. In fact, GZ took \(F_\infty(x) \equiv 1\), but we can include the effect of the next-leading term of \(O(x^{-10})\) at \(x \gg 1\) by giving a form for \(F_\infty(x)\) as
\[
 F_\infty(x) = \frac{(x - 1)^2 + \exp[a_\infty(r_s)]}{(x - 1)^2 + \exp[-a_\infty(r_s)]}, \tag{46}
\]
where \(a_\infty(r_s)\) is an adjustable parameter related to the coefficient of the next-leading term. Note that \(F_\infty(x) \equiv 1\) for \(a_\infty(r_s) \equiv 0\). In actual calculations, we find that \(a_\infty(r_s)\) plays an important role in fulfilling the third sum rule, Eq. (30).

E. Input data for the parametrization scheme
There are six free parameters, namely, \(n_0, n_\pm, a_\pm,\) and \(a_\infty\), in the definition of Eq. (34). The basic idea of GZ is to determine the first three by the interpolation between the accurate data of \(n(p)\) for \(1 \leq r_s \leq 5\) obtained by EPX [9] and the result in the limit of \(r_s \to \infty\) in which GZ assume that \(n(p)\) is reduced to that in the Wigner lattice, \(n_W(p)\), expressed as
\[
 n_W(p) = \frac{4\pi}{3} \left(\frac{p^2}{\pi m_0}\right)^{3/2} \exp\left(-\frac{p^2}{m_0}\right), \tag{47}
\]
with \(\omega = 0.8833 r_s^{-3/2}\) in a.u. In improving on the GZ scheme, we also adopt \(n_W(p)\) as basic information for \(r_s \gg 10\), but the EPX data are upgraded by the data for \(1 \leq r_s \leq 10\) obtained by GWΓ (or actually GWΓW) [10]. Then the actual parametrization formulas for \(n_0(r_s)\) and \(n_\pm(r_s)\) are slightly different from those in GZ. Our revised results for them are given, respectively, by
\[
n_0(r_s) = \frac{1 + t_1 r_s^2 + t_2 r_s^{5/2}}{1 + t_3 r_s^2 + t_4 r_s^{5/2}}, \tag{48}
\]
\[
n_-(r_s) = \frac{1 + v_1 r_s + v_2 r_s^{5/2}}{1 + v_3 r_s + v_4 r_s^{5/2} + v_5 r_s^{13/4}}, \tag{49}
\]
\[
n_+(r_s) = \frac{q_1 r_s + q_2 r_s^{5/2}}{1 + q_3 r_s^{1/2} + q_4 r_s^{3/2} + q_5 r_s^{13/4}}. \tag{50}
\]
with \(t_1 = 0.013 813 294 1, t_2 = 0.006 504 281 94, t_3 = 0.025 275 492 1, t_4 = 0.001 015 523 77, v_1 = 0.198 200 080, v_2 = 0.001 839 431 25, v_3 = 0.286 719 080, v_4 = 0.013 899 539 9, v_5 = 0.000 473 501 718, q_1 = 0.088 519 000, q_2 = 0.002 142 766 78, q_3 = 0.387 350 521, q_4 = 0.079 971 845 3, and q_5 = 0.000 551 585 578.

The obtained \(n_0(r_s)\) and \(n_\pm(r_s)\) are plotted in Fig. 3. We see that our results are about the same as those in GZ for \(r_s < 10\), but they are considerably different, especially for the case of \(n_-(r_s)\); ours change much more smoothly with the increase of \(r_s\) than those in GZ and eliminate the strange behavior of \(n_-(r_s)\) at \(r_s \approx 16\) in GZ.

Incidentally, if we assume that \(n(p)\) converges to \(n_W(p)\) in the low-density limit, we should assess this assumption by checking the three sum rules with this \(n_W(p)\) at \(r_s \to \infty\). In fact, the first two sum rules are easily found to be satisfied, as already mentioned in GZ, but a problem exists on the third one; this \(n_W(p)\) gives \(I_4 = 1/(2\pi \omega)\) and \(I_6 = 5/(4\pi^2 \omega^2)\) with \(\omega = p^2/(m_0\omega) = 4.1692/\sqrt{r_s}\). By substituting these \(I_4\) and \(I_6\) into Eq. (30), we obtain \(\lim_{r_s \to \infty} B(r_s) = 1.1868\), while \(\lim_{r_s \to \infty} B_{\text{MCS}}(r_s) = 1.064\), indicating the difference in about 10%. Because \(B_{\text{MCS}}(r_s)\) was determined with the input data only for \(r_s \leq 10\), we consider it more appropriate to amend \(B(r_s)\) slightly from \(B_{\text{MCS}}(r_s)\) into a form fulfilling the asymptotic value of 1.1868 as
\[
 B(r_s) = \frac{1 + [a_1 + (a_2 + a_3 r_s) r_s] \sqrt{r_s}}{3 + [b_1 + (b_2 + b_3 r_s) r_s] \sqrt{r_s}}, \tag{51}
\]
with \(a_1 = 2.161, a_2 = 0.4599, a_3 = 0.006679, b_1 = 1.594, b_2 = 0.4388,\) and \(b_3 = 0.005627\). In Fig. 4, this modified \(B(r_s)\) is plotted in comparison with \(B_{\text{MCS}}(r_s)\) to find that they are essentially the same for \(r_s \leq 10\). The function \(C(r_s)\) in Eq. (21) is also shown to see that \(C(r_s)\) correctly behaves asymptotically in the Wigner-lattice limit.

F. Calculated results
The remaining three parameters, \(a_\pm\) (or equivalently \(A_\pm\)) and \(a_\infty\), are determined so as to accurately satisfy the three sum rules at each \(r_s\). For \(n(p)\) calculated at \(r_s = 8\) with
use of three different forms, namely, Yasuhara, Overhauser, and GP, of $g(0)$ are shown in Fig. 5, together with those in the GZ scheme and GW [10]. All these results are essentially the same, assuring that the present scheme works very well to obtain accurate enough $n(p)$ satisfying three sum rules simultaneously.

In Fig. 6, the results of $n(p)$ calculated with the choice of $g(0) = g_Y(0)$ are shown for a wide range of $r_s$. In the metallic-density regime ($1 \leq r_s \leq 5$), the obtained $n(p)$ is about the same as that given in EPX [9] or GW [22]. Even in the dielectric-catastrophe regime, $n(p)$ behaves in a normal and well-known manner, as long as $r_s$ is smaller than about 12. With the further increase of $r_s$, however, it begins to behave rather differently from the normal one for $|p| < p_F$ and eventually for $r_s > 20$, it exhibits a novel feature in the sense that $n(p)$ becomes virtually flat for $|p| < p_F$, implying that the quasihole excitation energy at the center of the Fermi sphere is about the same as that near the Fermi surface. For $|p| > p_F$, on the other hand, this anomalous flat behavior is never seen in $n(p)$, indicating strong electron-hole asymmetric excitation spectra. Incidentally, a sign of this asymmetry has already been seen in the one-electron spectral function obtained in GW [10].

FIG. 4. Parametrized $B(r_s)$ and $C(r_s)$ as a function of $r_s$. The former is compared with the one proposed by Moroni, Ceperley, and Senatore, together with the value in the Wigner-lattice limit.

FIG. 5. An example of $n(p)$ calculated with use of three different forms, namely, Yasuhara, Overhauser, and GP, of $g(0)$ in Yasuhara (solid), GP (dotted-dashed), and Overhauser (dashed) forms at $r_s = 8$. Our results are compared with that in the GZ scheme as well as that in GW.

FIG. 6. Obtained $n(p)$ for (a) $1 \leq r_s \leq 16$ and (b) $16 \leq r_s \leq 22$.
Three sum rules for $g(0)$ are employed. For comparison, $A_{\pm}$ in GZ are also shown. (In GZ, $a_{\infty} = 0$.) The inset displays $A_{-1}$ for the region of $r_s$ in which $A_{-}$ is very large.

the rapid increase of $A_{-}$ for $r_s > 12$. As shown in the inset of Fig. 7, $A_{-}$ actually diverges at $r_s = r_s' = 22.4 \pm 0.4$, the error of which is deduced from the difference in $F_s'$ caused by the different choice of $g(0)$. For $r_s > r_s'$, our scheme does not work and fails to determine the three parameters, $A_{ \pm}$ and $a_{\infty}$, simultaneously satisfying three sum rules. We might be able to interpret this divergence of the Fermi-edge coefficient or the nonanalytic behavior at the Fermi surface as an indication of the occurrence of some non-Fermi-liquid phase, but at present, we do not know exactly whether this is the case or not, mainly because we cannot rule out the possibility of inadequacy of the postulated form in Eq. (34) for the case of $A_{-} \gg 1$ (or $r_s > 20$). In any case, for $r_s \gtrsim 12$, it is certain that some unusual situation due to electron correlation begins to appear, as we can see in Fig. 8 in which the fluctuation of the kinetic energy $\Delta KE$ becomes larger than the average one ($KE$).

III. DYNAMICAL STRUCTURE FACTOR

A. Basic equation to determine $S(q, \omega)$

At $T = 0$, with use of Eq. (2) for $Q^R_\epsilon(q, \omega)$, $S(q, \omega)$ can be cast into the form of

$$ S(q, \omega) = -\frac{1}{\pi} \frac{1}{V(q)} \Im \left[ \frac{1}{\epsilon^R(q, \omega)} \right], $$

with the retarded dielectric function $\epsilon^R(q, \omega)$, given by

$$ \epsilon^R(q, \omega) = 1 + V(q) \Pi^R(q, \omega) $$

$$ = 1 + V(q) \frac{\Pi^R_W(q, \omega)}{1 - G^R(q, \omega)V(q)\Pi^R_W(q, \omega)}. $$

Here Eq. (6) is employed to write $\Pi^R(q, \omega)$ in terms of $\Pi^R_W(q, \omega)$ and $G^R(q, \omega)$, the latter of which is given by the analytic continuation of $G_\epsilon(q, i\omega)$ to the real axis in the complex upper $\omega$ plane ($i\omega \to \omega + i0^+$). Thus our task to calculate $S(q, \omega)$ begins with obtaining both $\Pi^R_W(q, \omega)$ and $G^R(q, \omega)$.

B. Polarization function $\Pi^R_W(q, \omega)$

The function $\Pi^R_W(q, i\omega)$ in Eq. (7) is rewritten as

$$ \Pi^R_W(q, i\omega) = 2 \sum_{pF} \frac{n(p)}{\omega^2 + (\epsilon_{p+q} - \epsilon_p)^2} $$

$$ = Q_{z,iu} \Pi^R_W(z, iu), $$

with the function $P_{z,iu}$, introduced as

$$ P_{z,iu} = \frac{1}{2z} \int_0^\infty x dx n(x) \ln \left[ \frac{u^2 + (x + z)^2}{u^2 + (x - z)^2} \right], $$

where $x = \frac{|p|}{p_F}$, $z = |q|/2p_F$, and $u = \frac{\omega/4E_F}{z}$. By analytic continuation, $\Pi^R_W(q, \omega)$ is obtained as

$$ \Pi^R_W(q, \omega) = Q_{z,iu} \frac{mpF}{2\pi^2} P_{z,iu}(\omega + i0^+), $$

with $P_{z,iu}(\omega + i0^+)$, given by

$$ P_{z,iu}(\omega + i0^+) = \frac{1}{2z} \int_0^\infty x dx n(x) \ln \left[ u^2 - (x + z)^2 + i0^+ ight] $$

$$ - \ln \left[ u^2 - (x - z)^2 + i0^+ \right], $$

where $\ln(\omega)$ is so defined as $\ln(\omega) = \ln(|\omega|) + i\arg(\omega)$ with $\arg(\omega)$ the argument of $\omega$ in the upper $\omega$ plane being between 0 and $\pi$. In performing the numerical evaluation of this integral over the variable $x$, care must be exerted at both $x = |u - z|$ and $x = u + z$ in order to accurately obtain the principal values of the integral.

With $n(p)[\equiv n(x)]$ obtained in Sec. IIIF, we can calculate $\Pi^R_W(q, \omega)$ through Eqs. (56) and (57). The overall structure of the calculated $\Pi^R_W(q, \omega)$ does not depend much on $r_s$, in...
C. Dynamical local-field factor $G_s^R(q,\omega)$

There is a long history of research on the dynamical local-field factor and its parametrization [29,39–46]. Those studies are mainly motivated by the construction of the exchange-correlation kernel $f_{xc}(r,r';\omega)$ in the time-dependent density functional theory (TDDFT) and thus they are concerned with either $G_s(q,\omega)$ or $G_s^R(q,\omega)$, but not with $G_i(q,\omega)$. So far a parametrization form for $G_q(q,\omega)$ is given only by RA [28], proposing

$$G_q(q,\omega) = \frac{a_s(i\Omega)\alpha_{rs}}{1 + c_i(i\Omega)\alpha_{rs} + b_i(i\Omega)\alpha_{rs}^2},$$

(58)

with $\Omega \equiv z\omega = \omega/4E_F$. This form of $G_q(q,\omega)$ satisfies the rigorous limit due to Niklasson [37] at $|q| \to \infty$ as $G_q(q,\omega) \to 2(1 - g(0))/3$, irrespective of $\omega$.

The function $a_s(i\Omega)$ is so determined as to satisfy the constraints in the small- $|q|$ regime, namely, the compressibility sum rule [47–49] at $\Omega \to \infty$, leading to the following form:

$$a_s(i\Omega) = \lambda_s^{\infty} + \frac{\lambda_s^{(0)} - \lambda_s^{(\infty)}}{1 + \beta_1\gamma \Omega + (\beta_2\gamma \Omega)^2};$$

(59)

where $\lambda_s^{(0)}$ and $\lambda_s^{(\infty)}$ are, respectively, defined as

$$\lambda_s^{(0)} = \frac{\pi}{\kappa} \left[ \frac{1}{\Gamma_0} - \frac{\kappa F}{\kappa} \right],$$

(60)

$$\lambda_s^{(\infty)} = \frac{3}{5} - \frac{2}{\kappa} \frac{\pi}{\kappa} \frac{\partial \epsilon_c(r_s)}{\partial r_s} + 2\epsilon_c(r_s),$$

(61)

where the ratio of the compressibilities with and without the interactions, $\kappa$ and $\kappa F$, can be calculated as

$$\frac{\kappa F}{\kappa} = 1 - \frac{\alpha r_s}{\pi} + \frac{\alpha^2 r_s^3}{6} \left[ \frac{\partial^2 \epsilon_c(r_s)}{\partial r_s^2} - \frac{2\partial \epsilon_c(r_s)}{\partial r_s} \right].$$

(62)

As for the two functions, $c_i(i\Omega)$ and $b_i(i\Omega)$, in Eq. (58), by the consideration of the condition to obtain the maximum value of $4[1 - g(0)]/3$ for $G_q(q,\omega)$ at $z^2 \approx \Omega \to \infty$, RA gave the following forms:

$$c_i(i\Omega) = \frac{3}{4} \frac{\lambda_s^{(\infty)}}{1 - g(0)} - \frac{4}{3} - \frac{1}{\alpha_{rs}} + \frac{\lambda_s^{(\infty)}}{4(1 - g(0))},$$

(63)

$$b_i(i\Omega) = \frac{3a_s(i\Omega)}{1 + \gamma \Omega + \gamma_2 \Omega^2 + \gamma_3 \Omega^3 + \Omega^4} \times \frac{1}{1 + \gamma_1 \Omega + \gamma_2 \Omega^2 + \gamma_3 \Omega^3 + \Omega^4},$$

(64)

with the parameter $\gamma_i$ determined as

$$\gamma_i = \frac{9}{16} \frac{\lambda_s^{(\infty)}}{1 - g(0)} + 1 - \frac{3}{4} \frac{1}{\alpha_{RA}}.$$

(65)

In Eqs. (59), (63), and (64), six parameters, $\alpha_{RA}$, $\beta_1$, $\beta_2$, $\gamma_1$, $\gamma_2$, and $\gamma_3$, are at our disposal, but RA made the following choice: $\alpha_{RA} = 0.9, \beta_1 = 0, \beta_2 = 1, \gamma_1 = \gamma_3 = 4$, and $\gamma_2 = 6$.

A similar parametrization scheme was proposed by RA for $G_q(q,\omega) \equiv G_q(q,\omega) - G_i(q,\omega)$. As a matter of fact, with

FIG. 9. The retarded polarization function $\Pi_{WIL}(q,\omega)$ in comparison with $\Pi_{WIL}^R(q,\omega)$ at $r_s = 22$ for (a) real and (b) imaginary parts.

spite of the appearance of an anomalous feature in $n(p)$ for $r_s > 20$; as shown in Fig. 9, even at $r_s = 22$, the results of $\Pi_{WIL}^R(q,\omega)$ given as a function of $\omega$ at various values of $q$ (the solid curves) retain the main features of those of $\Pi_{WIL}^R(q,\omega)$ the Lindhard function in the retarded form (the dotted-dashed curves). We can understand this insensitivity of $\Pi_{WIL}^R(q,\omega)$ to the anomalous feature in $n(p)$ by paying attention to the fact that $\Pi_{WIL}^R(q,\omega)$ is mostly controlled by the sum rules for $n(p)$; the details of $n(p)$ are smeared out by the integral over the variable $x$ in Eq. (57).

Note, however, that there is a very important difference between $\Pi_{WIL}^R(q,\omega)$ and $\Pi_{WIL}^R(q,\omega)$; Im$\Pi_{WIL}^R(q,\omega)$ does not vanish only in the electron-hole single-pair excitation region in $q,\omega$ space, while basically Im$\Pi_{WIL}^R(q,\omega)$ is not zero but positive definite for $\omega > 0$ at any $q$ due to the inclusion of the multiple electron-hole pair excitations by the use of $n(p)$ instead of $n_0(p)$. For this reason, as long as Eq. (33) is employed, we do not need to introduce an artificial finite broadening width $\gamma$ in the numerical calculation of the dielectric function, in sharp contrast with the usual treatment of $\omega \to \omega + i\gamma$ in the calculation of the plasmon-peak structure in $S(q,\omega)$ with using $\Pi_{WIL}^R(q,\omega)$ or its simple extension in which no account is taken of the multiple electron-hole pair excitations.
FIG. 10. Difference between the “exact” value of $\varepsilon_c$ due to Perdew and Wang and the one calculated through the adiabatic connection formula with using the local-field factor in the original RA (the dotted-dashed curve), a simple version of the modified RA (the dashed curve), and an improved version of the modified RA (the solid curve) schemes.

use of Eq. (24), $G_n(q,i\omega)$ is given exactly as

$$G_n(q,i\omega) = G_n^{\text{exact}}(q,i\omega)$$

$$= \frac{1}{V(q)} \left[ \frac{1}{\Pi_0(q,i\omega)} - \frac{1}{\Pi_W(q,i\omega)} \right].$$

We have calculated $G_n^{\text{exact}}(q,i\omega)$ through Eq. (66) with $\Pi_W(q,i\omega)$ given by Eqs. (54) and (55) and compared with $G_n^{\text{RA}}(q,i\omega)$, the parametrized form for $G_n(q,i\omega)$ due to RA, to find that $G_n^{\text{RA}}(q,i\omega)$ is in fact very reliable; in particular, no appreciable difference can be seen for the quantities given by integrals over $q$ and $\omega$, such as $\varepsilon_c(r_c)$ obtained through the adiabatic connection formula, Eq. (27) in Ref. [29], in which we have calculated with use of either $G_1(q,i\omega) + G_n^{\text{RA}}(q,i\omega)$ or $G_1(q,i\omega) + G_n^{\text{exact}}(q,i\omega)$. With this assessment of the RA parametrization scheme, we can expect that the parametrized $G_n(q,i\omega)$ will also be reliable. Incidentally, this RA scheme comes to be known as a good feature [29]; it provides a quite accurate $\varepsilon_c(r_c)$ in reference to its “exact” value $\varepsilon_c^{\text{exact}}(r_c)$ given by Perdew and Wang [4] (see the dotted-dashed curve in Fig. 10).

By analytic continuation ($i\omega \to \omega + i0^+$), we obtain $G^R_n(q,\omega)$ from $G_n(q,i\omega)$ in Eq. (58), but with $\beta_s$ chosen in RA. $G^R_n(q,\omega)$ at small $q$ suffers from the existence of unphysical divergence at $\omega = \pm 4E_F/\gamma_s$. A simple way to eliminate this unphysical divergence while keeping the good feature of providing accurate $\varepsilon_c(r_c)$ is found to choose $\alpha_{\text{RA}} = 0.958/(1 + 0.006r_s)$, $\beta_1 = 0.8$, and $\beta_2 = 0.4$ with $\gamma_s$ unchanged. This simple version of the modified RA scheme gives better $\varepsilon_c(r_c)$ than the original RA scheme (see Fig. 10). A closer analysis of this scheme, however, reveals that unphysical divergence appears for $2p_e \lesssim |q| \lesssim 3p_e$ with $\gamma_s$ chosen as those in RA.

Under these circumstances, we have made an extensive search of suitable values for all free parameters in Eqs. (59), (63), and (64) with considering the following four criteria: (i) $G^R_n(q,\omega)$ contains no unphysical divergence for real $\omega$, (ii) $G^R_n(q,\omega)$ should be analytic in the upper complex $\omega$ plane, in accord with the causality condition [39,40], (iii) $G_n(q,i\omega)$ accurately provides $\varepsilon_c$ in a wide range of $r_s$, and (iv) $G^R_n(q,\omega)$ combined with $\Pi_W(q,\omega)$ gives the results of $S(q,\omega)$ in good agreement with those in GWI’ [25] for $1 \leq r_s \leq 5$.

As a result of this search, we have chosen the following set of parameters, which we call an improved version of the modified RA scheme: $\beta_1 = \beta_2 = 0.8$, $\gamma_1 = \gamma_2 = \gamma_3 = 1$, and

$$\alpha_{\text{RA}}(r_s) = \frac{\alpha_0}{1 + \left[ \alpha_1 + \alpha_2/(1 + \alpha_3 r_s + \alpha_4 r_s^2) \right] r_s},$$

with $\alpha_0 = 1.2110$, $\alpha_1 = 0.01064$, $\alpha_2 = 0.10296$, $\alpha_3 = -0.2910$, and $\alpha_4 = 0.2540$.

D. Ghost exciton mode $\tilde{\omega}_n(q)$

With $\Pi_W(q,i\omega)$ and $G_n(q,i\omega)$ thus determined, we can calculate $\Pi(q,i\omega)$ through Eq. (6) to find that it actually diverges at $i\omega = \pm i\tilde{\omega}_n(q)$ for $r_s > r'_s$ in accord with the discussion in Ref. [21]. Numerically, $\tilde{\omega}_n(q)$ can be determined by the search of zero of $\Pi(q,i\omega)$ for $\omega > 0$.

In Fig. 11(a), the obtained results of $\tilde{\omega}_n(q)$ are shown as a function of $q$ ($= |q|$) at several values of $r_s$ in the dielectric-catastrophe regime of $r_s > r'_s$. For small $q$, $\tilde{\omega}_n(q)$ increases in proportion to $q$, just like a sound mode, and “the sound velocity” $c_{ex}$ changes in proportion to $|\kappa_F/\kappa|$ with the coefficient $2\nu_F/\pi$ ($\nu_F$: the Fermi velocity) for $r_s$ near $r'_s$, as shown in Fig. 11(b). Note that this behavior of $c_{ex}$ is similar to that for “the exciton mode” identified by the peak position of $\Im e^R(q,\omega)$ for $r_s < r'_s$ [20]. Thus it is more appropriate to call the mode of $\tilde{\omega}_n(q)$ on the imaginary $\omega$ axis...
FIG. 12. Oscillator strength of the ghost exciton mode. Inset: Fraction of this oscillator strength to the full strengths in the limit of $q \to 0$, together with the sound velocity in units of $v_F$, plotted as a function of $r_s$.

“the ghost exciton mode” than “the ghost plasmon” which was suggested in Ref. [21].

The oscillator strength $f_{\text{ex}}(q)$ in the definition of $\Pi_\omega(q,i\omega)$ in Eq. (1) is determined by the evaluation of $[\omega - \tilde{\omega}_{\text{ex}}(q)]\Pi(q,i\omega)$ in the limit of $\omega \to \tilde{\omega}_{\text{ex}}(q)$ and the obtained results are shown in Fig. 12. Incidentally, the asymptotic behavior of $\Pi(q,i\omega)$ in Eq. (6) is found to be

$$\Pi(q,i\omega) \xrightarrow{\omega \to \infty} \frac{4\pi}{V(q)} \frac{n e^2}{m} \frac{1}{\omega^2}, \quad (68)$$

from which we can prove the $f$-sum rule for $S(q,\omega)$ as

$$\int_{-\infty}^{\infty} d\omega \omega S(q,\omega) = \frac{N q^2}{2m}. \quad (69)$$

On the other hand, $\Pi_{\|}(q,i\omega)$ behaves as

$$\Pi_{\|}(q,i\omega) \xrightarrow{\omega \to \infty} \frac{1}{V(q)} \frac{n e^2}{m} \frac{f_{\text{ex}}(q)}{\omega^2}. \quad (70)$$

Comparison of Eq. (70) with Eq. (68) indicates that the ghost exciton mode contributes to the full oscillator strengths with the fraction of $f_{\text{ex}}(q)/4\pi$, which becomes more than 80% at $q \to 0$ for $r_s > 14$. Thus, in such a dilute electron gas, we come to notice that not the plasmon but the exciton mode will play a main role in the whole excitation spectra.

E. Calculated results of $S(q,\omega)$

With $\Pi_{\omega}^R(q,\omega)$ and $G_R^e(q,\omega)$ already given, we can calculate $S(q,\omega)$ through Eqs. (52) and (53). As mentioned before, in the usual metallic region ($1 \leq r_s \leq 5$), the form of $G_R^e(q,\omega)$ is finely tuned to reproduce the results of $S(q,\omega)$ that are already obtained in Ref. [25]. As illustrated in Fig. 1(a) for $r_s = 4$, the structure of $S(q,\omega)$ is featured by the single plasmon peak and the exciton contribution appears not as a peak but only as a shoulder structure in the low-$\omega$ region. (To be more definite, see the structure “a” specified in Fig. 1 in Ref. [25].)

Even in the dielectric-catastrophe regime ($r_s > r_s^c$), the main feature of $S(q,\omega)$ hardly changes at $r_s$ near $r_s^c$, but as $r_s$ increases further, the shoulder structure due to the excitonic effect gradually evolves into a broad peak, as illustrated in Fig. 13(a) at $r_s = 8$. The peak becomes sharper with the further increase of $r_s$ and appears as a clear peak for $r_s \approx 10$. Eventually for $r_s \gtrsim 14$, combined with the plasmon peak,
S(q,ω) is characterized by a twin-peak structure, as shown at rs=16 in Fig. 13(b). At rs=20 or larger, “the excitonic peak” grows even bigger than the plasmon one [see Fig. 1(b)].

In Fig. 14, we have plotted ωex(q) the excitonic peak position (including the shoulder position, if a peak structure is not well identified) at each q in (q,ω) space. This plot shows that ωex(q) is always inside the single-pair excitation region, as it should be for the excitonic effect working on an electron-hole single-pair excitation.

An even more interesting fact is that if ωex(q) is in the region of ω ≤ (2pqq−q^2)/2m, the corresponding peak in S(q,ω) is very sharp. In particular, ωex(q) becomes lowest if it lies just on this boundary and the highest peak in S(q,ω) appears in its very vicinity. Furthermore, with the increase of rs, this lowest-energy peak position (qmin,ωex(qmin)) becomes lower approximately in proportion to rs along the boundary curve, so that with the further increase of rs up to about 30, we may imagine a critical situation of qmin → 2pF and ωex(qmin) → 0 by extrapolation. If this critical situation were actually realized, we might expect the occurrence of a very exotic phase transition brought about by the spontaneous excitation of a macroscopic number of excitons or “the exciton condensation.”

**F. Retarded dielectric function εR(q,ω)**

Let us make a detailed analysis of the retarded dielectric function εR(q,ω) in order to investigate the relation between the excitonic-peak position (or the excitonic collective mode) ωex(q) and the ghost exciton mode ωex(q).

In the conventional metals without the dielectric catastrophe as represented by the electron gas at rs=4, the overall behavior of εR(q,ω) is well known and rather simple; as shown in Fig. 15(a) for its real part in (q,ω) space, there is only a single singular point at q=ω=0 in this function, characterized by εR(q,ω) ≈ 1−ω_1^2/ω^2 in the limit of ω → 0 with keeping vFq/ω ≪ 1 (the ω limit) and εR(q,ω) ≈ 1+(κ/sFq )vFq/ω^2 in the limit of q → 0 with vFq/ω ≫ 1 (the q limit), where

\[ \omega_{pl} = \sqrt{\frac{4\pi e^2 n/m}{\epsilon_0^2}} \]

is the plasmon energy at q → 0 and \[ q_{TF} = \sqrt{\frac{4\pi e^2 m p_F/\pi}{\epsilon_0^2}} \]

is the Thomas-Fermi screening constant. Associated with this singular point at the origin of (q,ω) space, the plasmon emerges as a collective mode satisfying εR(q,ω) ≈ 0 at ω ≈ ω_{pl} for small q.

In the dielectric-catastrophe regime (rs>r_c), there appears the ghost exciton mode, but as long as ωex(q) is positive, the mode is not a pole on the real axis in the complex ω plane, indicating its irrelevance from a physical point of view. At both q=0 and qex≠0 at which ωex(q) becomes zero [see Fig. 11(a)], however, the pole is situated on the real axis and thus it must have direct physical relevance.

In fact, we find that εR(q,ω) contains a couple of singularities, one at the origin of (q,ω) space and the other at q=qex and ω=0, as illustrated in Fig. 15(b) for the case of rs=8. The singularity occurring at the origin behaves in much the same way as that in the conventional metals, excluding a possibility of the observation of any exotic effects associated with this singularity. The only difference in the case of negative
\[ \epsilon^R(q, \omega) \approx 1 + \left( \frac{p_F}{q} \right)^2 \frac{1}{A_{ex}(q - q_{ex})/p_F - i B_{ex} \omega/E_F}, \] (71)

where the coefficients, \( A_{ex} \) and \( B_{ex} \), are given by

\[ A_{ex} = \frac{p_F}{q} \frac{d f(q_{ex}, 0)}{dq_{ex}} \] and \( B_{ex} = -\lim_{\omega \to 0} E_F \text{Im} f(q_{ex}, \omega)/\omega \) with \( f(q, \omega) \), defined in reference to Eq. (53) by

\[ f(q, \omega) = \frac{\pi}{2 \alpha r_s} \frac{1}{P_{\text{th}}(q, \omega)} \left( \frac{p_F}{q} \right)^2 G^R_{\text{th}}(q, \omega). \] (72)

Note that \( f(q_{ex}, 0) = 0 \) by the definition of \( q_{ex} \).

In Fig. 16(a), the obtained \( q_{ex} \), \( A_{ex} \), and \( B_{ex} \) are plotted as a function of \( r_s \). At \( r_s = r_s' \), \( A_{ex} \) vanishes, removing this singularity from \( \epsilon^R(q, \omega) \), but \( B_{ex} \) is positive definite for \( r_s > r_s' \) and thus this singularity always exists in the dielectric-catastrophe regime. With the increase of \( r_s \), \( q_{ex} \) increases monotonically and at \( r_s \approx 9.51 \) it becomes equal to \( 2p_F \), which is the boundary at the electron-hole single-pair excitation. Due to this transition across the boundary, both \( A_{ex} \) and \( B_{ex} \) exhibit anomalous behavior at \( r_s \approx 9.51 \). Because \( B_{ex} \) is much decreased at \( r_s \approx 9.51 \) and becomes smaller further for \( r_s > 9.51 \), the effect of this singularity on \( \epsilon^R(q, \omega) \) is gradually enhanced with the increase of \( r_s \).

In Fig. 16(b), we have given an example of the comparison between the approximate form for \( \epsilon^R(q, \omega) \) in Eq. (71) and the full result of \( \epsilon^R(q, \omega) \) in Eq. (53) calculated at \( r_s = 22 \), from which we can confirm the accuracy of this approximate form in the neighborhood of the singular point at \( (q, \omega) = (q_{ex}, 0) \). This figure also shows that the excitonic-peak position providing the maximum height in \( S(q, \omega) \), \( (q_{max}, \omega_{ex}(q_{max})) \), is actually coincident with the point in \( (q, \omega) \) space at which \( \epsilon^R(q, \omega) \approx 0 \), validating to call \( \omega_{ex}(q) \) "the excitonic collective mode." In this way, the excitonic collective mode is brought about by the singular behavior of \( \epsilon^R(q, \omega) \) associated with the singularity at \( (q_{ex}, 0) \) which is originally induced by the ghost exciton mode.

Finally, in Fig. 17, \( \epsilon^R(q, \omega) \) given in Eq. (53) is plotted at \( r_s = 22 \) in the whole \( (q, \omega) \) space in order to fully represent the typical behavior of \( \epsilon^R(q, \omega) \) in the dielectric-catastrophe regime. As a general feature, \( \epsilon^R(q, \omega) \) contains a couple of singular points. Associated with each singularity, there appears a collective mode at which \( \epsilon^R(q, \omega) \approx 0 \), leading to the
double-peak structure in $S(q, \omega)$, one for the plasmon and the other for the excitonic collective mode, as shown in Fig. 1(b).

IV. CONCLUSION AND DISCUSSION

In this paper, we have calculated the momentum distribution function $n(p)$ and the dynamical structure factor $S(q, \omega)$ in the three-dimensional (3D) electron gas at low densities, i.e., $r_s > 5.25$, in which the electronic compressibility is negative. The obtained $n(p)$ is considered to be sufficiently accurate, because it rigorously satisfies not only the exact asymptotic behavior but also the three sum rules, Eqs. (3)–(5), the last of which is successfully derived in this work. The obtained $S(q, \omega)$ is also considered to be sufficiently accurate, because the two ingredients to construct $S(q, \omega)$, namely, $\Pi_{\text{W1}}(q, \omega)$ and $G^R_{\text{qo}}(q, \omega)$, are both reliably determined in accordance with all the known constraints that must be fulfilled for correct evaluation of those quantities. For $r_s > 10$, the calculated $S(q, \omega)$ exhibits a peak structure due to the excitonic collective mode in addition to the well-known plasmon peak. With the increase of $r_s$, this new peak structure grows steadily and eventually for $r_s > 20$ it dominates the plasmon peak. Associated with this excitonic collective mode, a singularity is found for the first time in $\varepsilon R(q, \omega)$ at $q \approx 2p_F$ and $\omega = 0$, which is the direct physical consequence of the appearance of the ghost exciton mode for $r_s > 5.25$.

Four comments are in order:

(i) Although we have treated the 3D electron gas in this paper, exactly the same physics will be found in the 2D electron gas for $r_s > 20$. We need to make a further study of the possibilities of such a phase transition, but at the same time, we need to take account of the possibility of a partially spin-polarized state for $20 < r_s < 40$ [5], suggesting that we investigate the fate of the excitonic collective mode in the spin-polarized state as well as the coupling between charge and spin channels, a difficult but very intriguing problem left in the future.

(ii) Physically, if the excitonic collective mode is a dominant polarization process in the charge response to an external point-charge perturbation, we may imagine that the screening effect will be much more reduced than that in the usual metals due to the fact that the excitation of tightly bound electron-hole pairs does not contribute to screening, indicating that the Hartree-Fock (HF) approximation may work well in the evaluation of some physical quantities. This might be the reason why Ilani et al. [51] found that HF described their experimental results well in the metallic state at negative $\kappa$.

(iii) As mentioned in Secs. II F and III E, we find indications of some exotic electronic phase transition of the 3D electron gas for $r_s > 20$. We need to make a further study of the possibilities of such a phase transition, but at the same time, we need to take account of the possibility of a partially spin-polarized state for $20 < r_s < 40$ [5], suggesting that we investigate the fate of the excitonic collective mode in the spin-polarized state as well as the coupling between charge and spin channels, a difficult but very intriguing problem left in the future.

(iv) Finally, we remark on the similarity and difference between the plasma and the excitonic collective modes. Due to $\varepsilon R(q, \omega) \approx 0$ at each mode in the relation of $D(q, \omega) = \varepsilon R(q, \omega) E(q, \omega)$, there exists a wave-like charge-density oscillation as an eigenmode, accompanied by a finite electric field $E(q, \omega)$ even in the absence of an external force [i.e., $D(q, \omega) = E(q, \omega) = 4\pi e P(q, \omega) \approx 0$]. The associated electric polarization $P(q, \omega)$ is made of collective electron-hole excitations and works as a restoring force. These charge-density oscillations can be quantized as bosons, just as the plasma oscillations quantized into the plasmons. In spite of those similarities, there is an important difference in the correlation among excited electrons and holes: for the plasmons, because its energy is larger than $E_F$, all excited electrons and holes are uncorrelated, as can be well treated in RPA. For the excitonic collective modes, on the other hand, the excitations occur as a collection of excitons, indicating no polarization field in the long-wavelength limit and thus the absence of the mode at $|q| \to 0$; the polarization appears, if $|q|$ is of the order of $2p_F$ or the inverse of the exciton binding radius. Incidentally, if we consider the exotic phase mentioned in (iii) in terms of a spontaneous excitation of this charge-density oscillation, it might be regarded as a CDW state in the sense of not nesting-driven but Overhauser [52,53].

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